

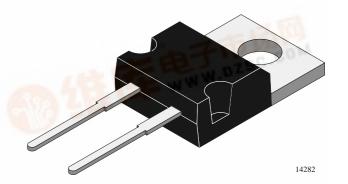
BYT106/1300

Vishay Telefunken

Fast Recovery Silicon Power Rectifier

Features

- Multiple diffusion
- Low switch on power losses
- Good soft recovery behaviour
- Fast forward recovery time
- Fast reverse recovery time
- Low reverse current
- Very good reverse current stability at high temperature
- Low thermal resistance



Applications

Fast rectifiers in S.M.P.S
Freewheeling diodes and snubber diodes in motor control circuits

Absolute Maximum Ratings

 $T_i = 25^{\circ}C$

Parameter	Test Conditions	Туре	Symbol	Value	Unit
Reverse voltage =Repetitive peak reverse voltage			$V_R = V_{RRM}$	1300	V
Peak forward surge current	t _p =10ms, half sinewave	et (I _{FSM}	50	Α
Repetitive peak forward current	1990		I _{FRM}	15	Α
Average forward current	57\\(P)		I _{FAV}	5	Α
Junction and storage temperature range	1014		T _j =T _{stg}	-40+150	°C

Maximum Thermal Resistance

 $T_i = 25^{\circ}C$

Parameter	Test Conditions	Symbol	Value	Unit
Junction case		R _{thJC}	2.4	K/W
Junction ambient		R _{thJA}	85	K/W

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Electrical Characteristics

 $T_i = 25^{\circ}C$

Parameter	Test Conditions	Type	Symbol	Min	Тур	Max	Unit
Forward voltage	I _F =5A		V_{F}			1.9	V
	I _F =5A, T _j =100°C		V_{F}			1.9	V
Reverse current	$V_R = V_{RRM}$		I _R			10	μΑ
	V _R =V _{RRM} , T _j =100°C		I _R			0.2	mA
Forward recovery time	I _F =5A, di _F /dt≦50A/μs		t _{fr}		350		ns
Turn on transient peak voltage			V_{FP}		7		V
Reverse recovery time	I _F =0.5A, I _R =1A, i _R =0.25A		t _{rr}			120	ns

Characteristics $(T_j = 25^{\circ}C \text{ unless otherwise specified})$

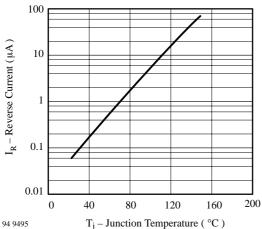
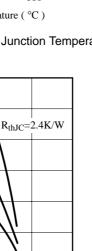


Figure 1. Typ. Reverse Current vs. Junction Temperature



200

160

Figure 2. Max. Average Forward Current vs. **Ambient Temperature**

 T_{amb} – Ambient Temperature ($^{\circ}C$)

120

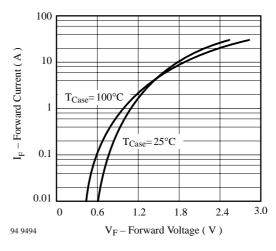


Figure 3. Typ. Forward Current vs. Forward Voltage

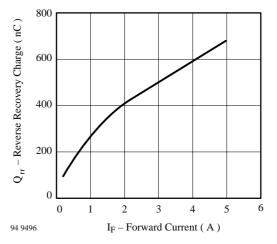


Figure 4. Reverse Recovery Charge vs. Forward Current

 $R_{thJA} = 5K/W$

 $R_{thJA} \!\!=\!\! 85 K/W$

 $R_{thJA} = 10 K/W$

I_{FAV}- Average Forward Current (A)

94 9493





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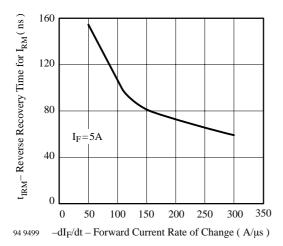


Figure 5. Reverse Recovery Time for I_{RM} vs. Forward Current Rate of Change

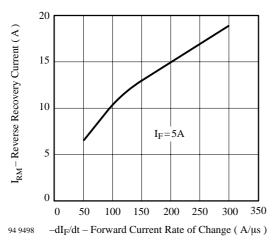


Figure 6. Reverse Recovery Current vs. Forward Current Rate of Change

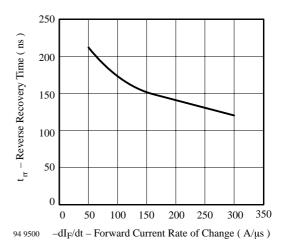


Figure 7. Reverse Recovery Time vs. Forward Current Rate of Change

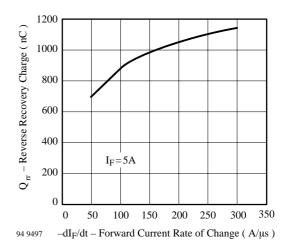


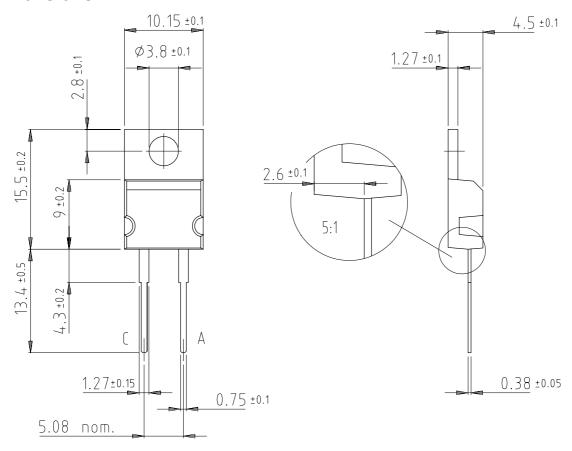
Figure 8. Reverse Recovery Charge vs. Forward Current Rate of Change

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Dimensions in mm



Plastic case JEDEC DO 220 Cathode connected with metallic surface



14276



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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems

with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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